74HC4053; 74HCT4053

Triple 2-channel analog multiplexer/demultiplexer

Rev. 10 — 5 March 2020

Product data sheet

1. General description

The 74HC4053; 74HCT4053 is a triple single-pole double-throw analog switch (3x SPDT) suitable for use in analog or digital 2:1 multiplexer/demultiplexer applications. Each switch features a digital select input (Sn), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ). A digital enable input (\overline{E}) is common to all switches. When \overline{E} is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Wide analog input voltage range from -5 V to +5 V
- Complies with JEDEC standard no. 7A
- Low ON resistance:
 - 80 Ω (typical) at V_{CC} V_{EE} = 4.5 V
 - 70 Ω (typical) at V_{CC} V_{EE} = 6.0 V
 - 60 Ω (typical) at V_{CC} V_{EE} = 9.0 V
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- · Typical 'break before make' built-in
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- · Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

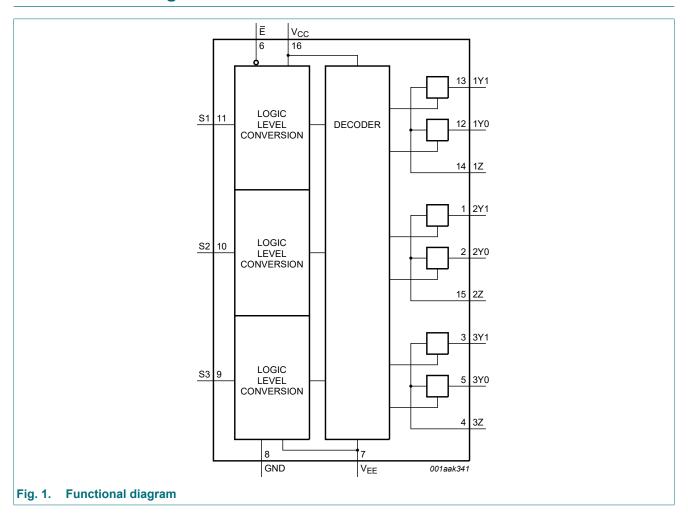


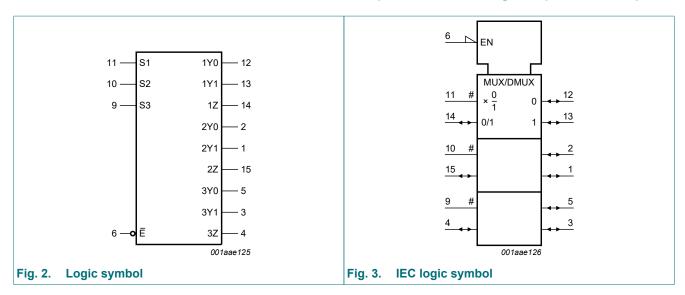
4. Ordering information

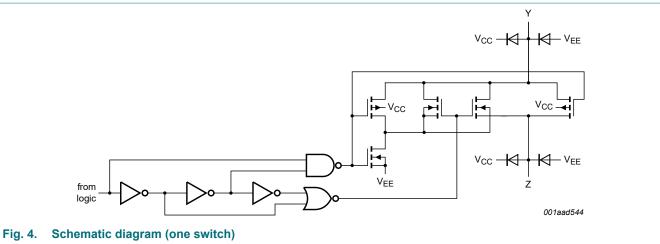
Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74HC4053D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1	
74HCT4053D			body width 3.9 mm		
74HC4053DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1	
74HC4053PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1	
74HCT4053PW			body width 4.4 mm		
74HC4053BQ	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1	
74HCT4053BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm		

5. Functional diagram



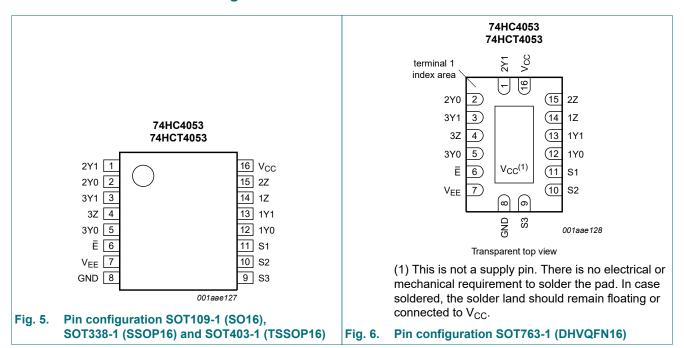




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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
E	6	enable input (active LOW)
V _{EE}	7	supply voltage
GND	8	ground supply voltage
S1, S2, S3	11, 10, 9	select input
1Y0, 2Y0, 3Y0	12, 2, 5	independent input or output
1Y1, 2Y1, 3Y1	13, 1, 3	independent input or output
1Z, 2Z, 3Z	14, 15, 4	common output or input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Inputs		Channel on
E	Sn	
L	L	nY0 to nZ
L	Н	nY1 to nZ
Н	X	switches off

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V}$ (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage	[1]	-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	-0.5 V < V _{SW} < V _{CC} + 0.5 V	-	±25	mA
I _{EE}	supply current		-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[2]	-	500	mW
Р	power dissipation	per switch	-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current will flow out of terminals nYn, and in this case there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

9. Recommended operating conditions

Table 5. Recommended operating conditions

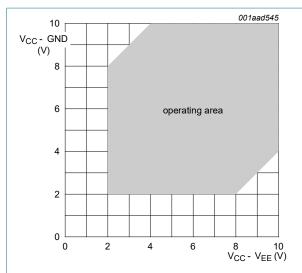
Symbol	Parameter	Conditions	7	74HC405	3	7	4HCT405	3	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage	see <u>Fig. 7</u> and <u>Fig. 8</u>							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{CC} - V _{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V_{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	31	-	-	-	ns/V

^[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT338-1 (SSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package: Ptot derates linearly with 11.2 mW/K above 106 °C.





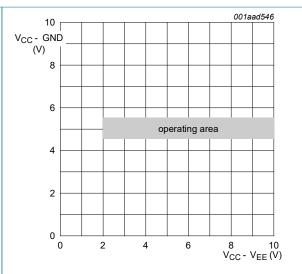


Fig. 8. Guaranteed operating area as a function of the supply voltages for 74HCT4053

10. Static characteristics

Table 6. R_{ON} resistance per switch for 74HC4053 and 74HCT4053

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see <u>Fig. 9</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053: V_{CC} - GND or V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4053: V_{CC} - GND = 4.5 V and 5.5 V, V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 25	5 °C						
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	100	180	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	90	160	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	70	130	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	70	120	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	60	105	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	90	160	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	65	120	Ω
ΔR _{ON}	ON resistance mismatch	$V_{is} = V_{CC}$ to V_{EE}					
	between channels	V _{CC} = 2.0 V; V _{EE} = 0 V	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	9	-	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	8	-	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	6	-	Ω

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C						
R _{ON(peak)}	ON resistance (peak)	V _{is} = V _{CC} to V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	225	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	200	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	165	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	175	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μ A		-	-	150	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	130	Ω
		$V_{is} = V_{CC}$					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	200	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	175	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	150	Ω
T _{amb} = -4	0 °C to +125 °C						
R _{ON(peak)}	ON resistance (peak)	V _{is} = V _{CC} to V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	270	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μ A		-	-	180	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	160	Ω
		$V_{is} = V_{CC}$					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	180	Ω

^[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

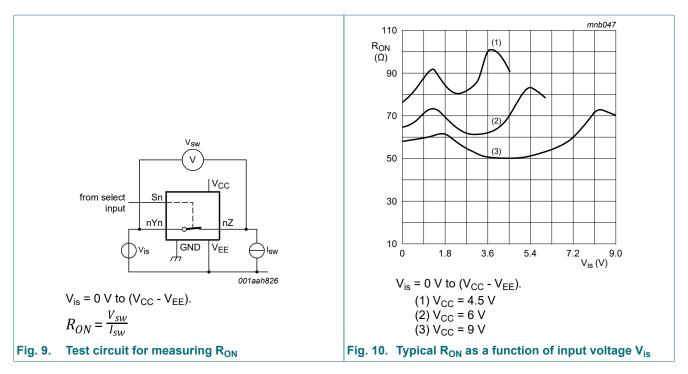


Table 7. Static characteristics for 74HC4053

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

Vos is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C				1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
I _I	input leakage current	V _{EE} = 0 V; V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±0.1	μΑ
		V _{CC} = 10.0 V	-	-	±0.2	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Fig. 11}$				
		per channel	-	-	±0.1	μA
		all channels	-	-	±0.1	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Fig. } 12$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_{EE} = 0 \text{ V}; V_{I} = V_{CC} \text{ or GND}; V_{is} = V_{EE} \text{ or } V_{CC};$ $V_{os} = V_{CC} \text{ or } V_{EE}$				
		V _{CC} = 6.0 V	-	-	8.0	μΑ
		V _{CC} = 10.0 V	-	-	16.0	μΑ
Cı	input capacitance		-	3.5	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -4	40 °C to +85 °C				1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
l _l	input leakage	V _{EE} = 0 V; V _I = V _{CC} or GND				
	current	V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; Fig. 11$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Fig. } 12$	-	-	±1.0	μΑ
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	80.0	μΑ
		V _{CC} = 10.0 V	-	-	160.0	μA
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage	V _{EE} = 0 V; V _I = V _{CC} or GND				
	current	V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Fig. } 12$	-	-	±1.0	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	160.0	μΑ
		V _{CC} = 10.0 V	-	-	320.0	μΑ

Table 8. Static characteristics for 74HCT4053

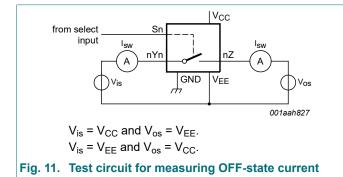
Voltages are referenced to GND (ground = 0 V).

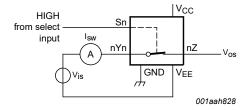
 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C			1		
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±0.1	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.1	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	16.0	μA
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; V_{EE} = 0 V	-	50	180	μA
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160.0	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	225	μА
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320.0	μΑ
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; V_{EE} = 0 V	-	-	245	μΑ





 V_{is} = V_{CC} and V_{os} = open-circuit. V_{is} = V_{EE} and V_{os} = open-circuit.

Fig. 12. Test circuit for measuring ON-state current

11. Dynamic characteristics

Table 9. Dynamic characteristics for 74HC4053

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Fig. 15.

V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	15	60	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	4	10	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	\overline{E} to $V_{os}; R_{L} = \infty \ \Omega; see \ \underline{Fig. 14}$ [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	75	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	25	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	21	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	20	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	63	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	21	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	18	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	17	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [4]	-	36	-	pF
T _{amb} = -4	10 °C to +85 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				T
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	75	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	13	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	10	ns
t _{on}	turn-on time	\overline{E} to V_{os} ; $R_L = \infty \Omega$; see $\overline{Fig. 14}$ [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	275	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	47	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	39	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	275	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	47	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		_	39	ns

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Fig. 14}$ [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	36	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	36	ns
T _{amb} = -	40 °C to +125 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to $V_{os};R_{L}=\infty\Omega;see\underline{Fig.}\underline{14}$				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Fig. 14}$ [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	44	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	44	ns
	1			1	1	

^[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

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ton is the same as t_{PZH} and t_{PZL}.
 t_{off} is the same as t_{PZH} and t_{PLZ}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz;

N = number of inputs switching; $\Sigma\{(C_L + C_{sw}) \times {V_{CC}}^2 \times f_o\}$ = sum of outputs;

 C_L = output load capacitance in pF; C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics for 74HCT4053

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Fig. 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	25 °C		'				
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u>	[1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	5	12	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	4	8	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u>	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	27	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	23	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	16	34	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	25	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	21	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	16	34	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Fig. 14}$	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	24	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	20	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	15	31	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	22	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	19	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	15	31	ns
C _{PD}	power dissipation capacitance	per switch; V_I = GND to V_{CC} - 1.5 V	[4]	-	36	-	pF
T _{amb} = -	40 °C to +85 °C		'		1		'
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13	[1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	10	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u>	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	60	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	43	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	60	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	43	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Fig. 14}$	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	55	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	39	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	55	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V			_	39	ns

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C		1		1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V_{os} ; R_{L} = 1 k Ω ; see $\underline{Fig. 14}$ [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see Fig. 14 [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14 [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns

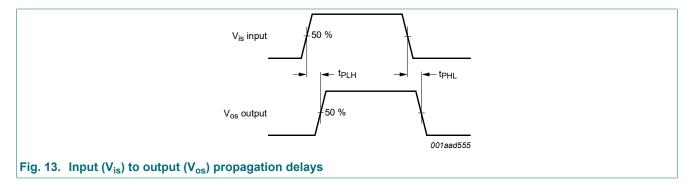
- t_{pd} is the same as t_{PHL} and t_{PLH} . t_{on} is the same as t_{PZH} and t_{PZL} .
- [2]
- t_{off} is the same as t_{PHZ} and t_{PLZ} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz;

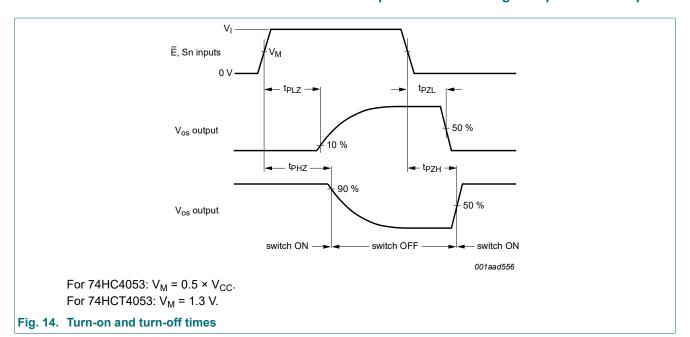
N = number of inputs switching; $\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ = sum of outputs;

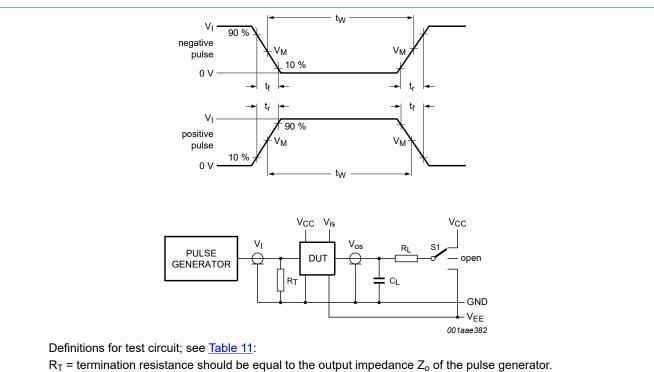
 C_L = output load capacitance in pF; C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.



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 C_L = load capacitance including jig and probe capacitance.

 R_{l} = load resistance.

S1 = Test selection switch.

Fig. 15. Test circuit for measuring AC performance

Table 11. Test data

Test	Input			Load	Load		
	V _I [1]	V _{is}	t _r , t _f	t _r , t _f		R _L	
			at f _{max}	other [2]			
t _{PHL} , t _{PLH}	V _{CC}	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open
t _{PZH} , t _{PHZ}	V _{CC}	V _{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V _{EE}
t _{PZL} , t _{PLZ}	V _{CC}	V _{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V _{CC}

^[1] For 74HCT4053: V_I = 3 V

11.1. Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; T_{amb} = 25 °C; C_L = 50 pF.

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	f_i = 1 kHz; R_L = 10 kΩ; see <u>Fig. 16</u>				
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	0.04	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	0.02	-	%
		f_i = 10 kHz; R_L = 10 kΩ; see Fig. 16				
		$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	-	0.12	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	0.06	-	%
α_{iso}	isolation (OFF-state)	R_L = 600 Ω; f_i = 1 MHz; see Fig. 17				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [1]	-	-50	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [1]	-	-50	-	dB
Xtalk crosstalk	crosstalk	between two switches/multiplexers; R_L = 600 Ω ; f_i = 1 MHz; see Fig. 18				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [1]	-	-60	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [1]	-	-60	-	dB
V _{ct} crosstalk voltage		peak-to-peak value; between control and any switch; $R_L = 600 \Omega$; $f_i = 1 \text{ MHz}$; \overline{E} or Sn square wave between V_{CC} and GND; $t_r = t_f = 6 \text{ ns}$; see Fig. 19				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	110	-	mV
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	220	-	mV
f _(-3dB)	-3 dB frequency	R_L = 50 Ω; see <u>Fig. 20</u>				
	response	$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [2]	-	160	-	MHz
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [2]	-	170	-	MHz

^[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

^[2] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

^[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

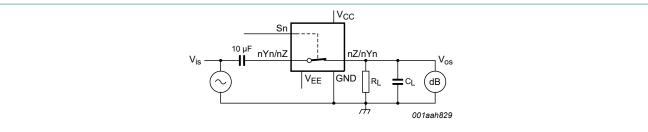
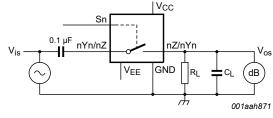


Fig. 16. Test circuit for measuring sine-wave distortion



 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 600 Ω; R_S = 1 kΩ. a.Test circuit

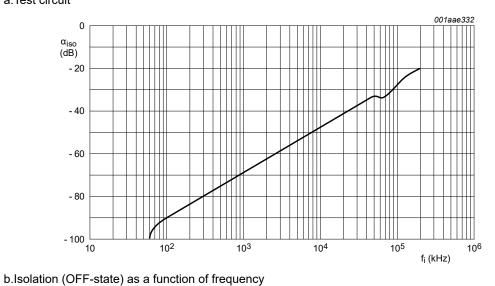
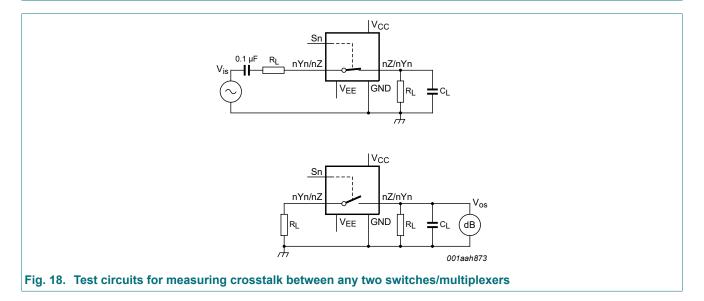


Fig. 17. Test circuit for measuring isolation (OFF-state)



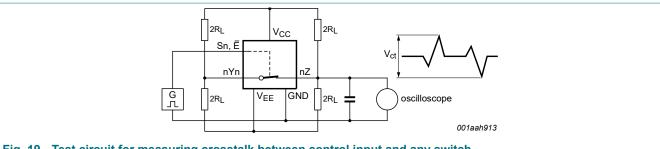
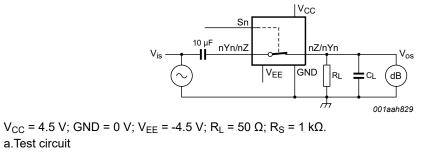
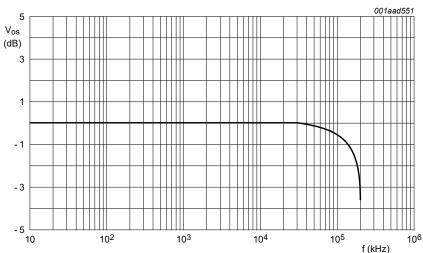


Fig. 19. Test circuit for measuring crosstalk between control input and any switch



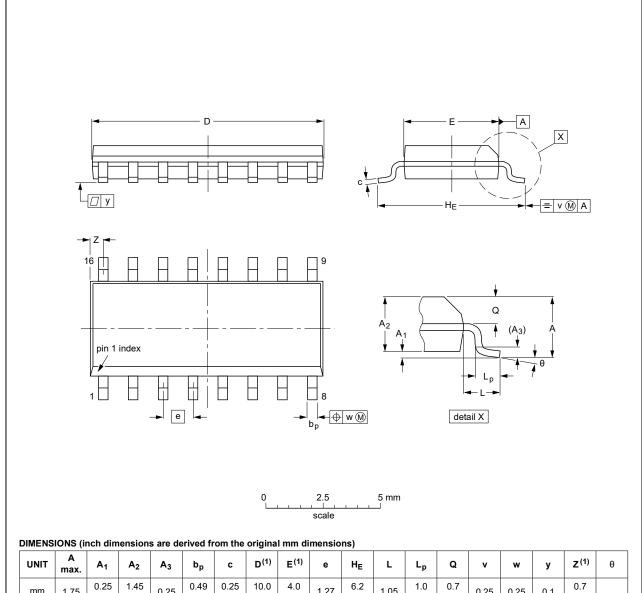


b. Typical frequency response Fig. 20. Test circuit for frequency response

12. Package outline



SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19

Fig. 21. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

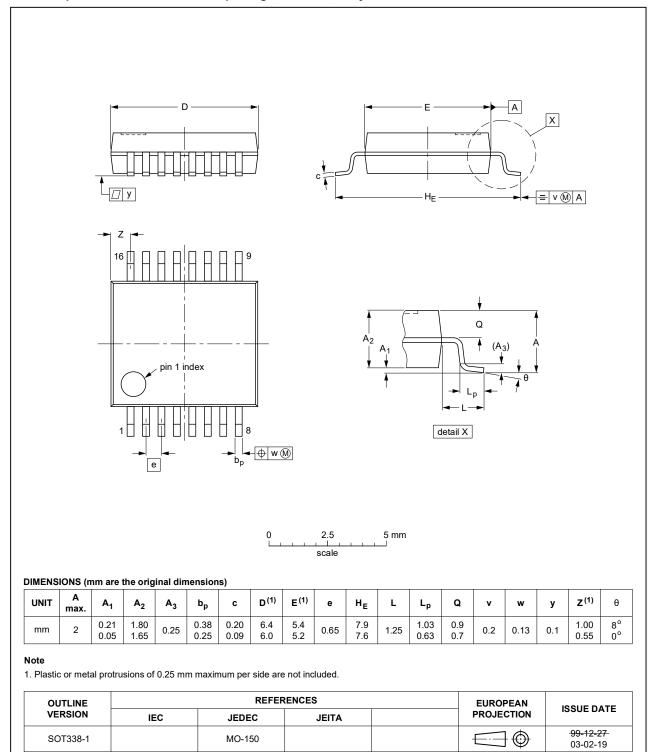


Fig. 22. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

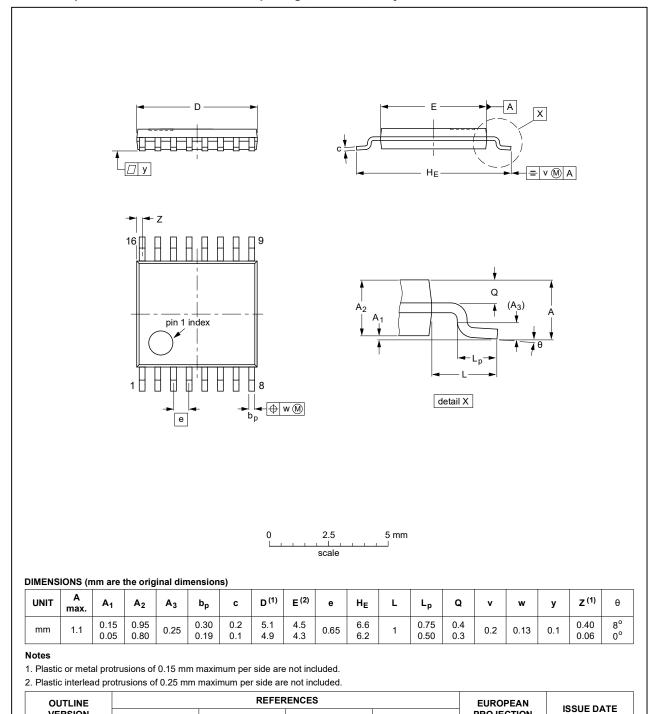


Fig. 23. Package outline SOT403-1 (TSSOP16)

IEC

JEDEC

MO-153

VERSION

SOT403-1

JEITA

99-12-27

03-02-18

PROJECTION

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

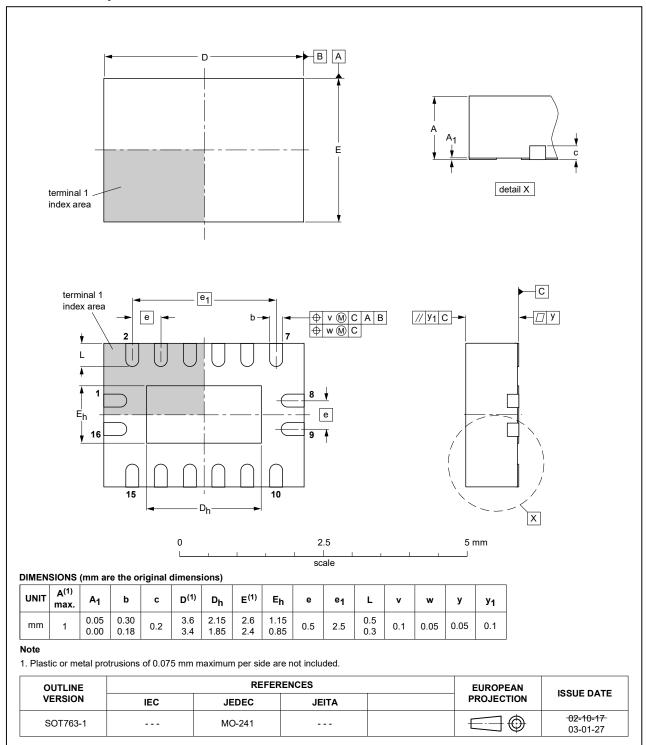


Fig. 24. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

Table 13. Abbreviations

Acronym	Description					
CDM	Charged Device Model					
ESD	ElectroStatic Discharge					
НВМ	Human Body Model					
MM	Machine Model					

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes					
74HC_HCT4053 v.10	20200305	Product data sheet	-	74HC_HCT4053 v.9					
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74HCT4053DB (SOT338-1) removed. Table 4: Derating values for P_{tot} total power dissipation updated. 								
74HC_HCT4053 v.9	20160210	Product data sheet	-	74HC_HCT4053 v.8					
Modifications:	Type number	Type numbers 74HC4053N and 74HCT4053N (SOT38-4) removed.							
74HC_HCT4053 v.8	20120719	Product data sheet	-	74HC_HCT4053 v.7					
Modifications:	CDM added	to features.							
74HC_HCT4053 v.7	20111213	Product data sheet	-	74HC_HCT4053 v.6					
Modifications:	Legal pages	updated.							
74HC_HCT4053 v.6	20110511	Product data sheet	-	74HC_HCT4053 v.5					
74HC_HCT4053 v.5	20110118	Product data sheet	-	74HC_HCT4053 v.4					
74HC_HCT4053 v.4	20060509	Product data sheet	-	74HC_HCT4053 v.3					
74HC_HCT4053 v.3	20060315	Product data sheet	-	74HC_HCT4053_CNV v.2					
74HC_HCT4053_CNV v.2	19901201	Product specification	_	-					

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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